

SO310A Optical modulation Photo IC

1. Features

- Asynchronous detection
- Allowable background illuminance: 2000 lx Min.
- Light detection level: 0.4µW/mm² Typ.
- Digital output
- Light on / Dark on Selection

2. Applications

Paper detection in office machines (Copier, Fax machines, ETC.)

• Photo sensor switches

4. Description

The SO310A is an asynchronous type light modulation photo IC designed for reliable detection even under disturbance background light. A photodiode, preamplifier, comparator, voltage regulator & etc. are all integrated on a monolithic photo IC chip.

3. Block Diagram





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5. Specifications

5.1 Absolute Maximum Ratings

				(Ta = 25 °C)
ITEM	Symbol	Min	Max	Unit
Supply Voltage	VDD		6	V
Operating temp.	Topr.	-25	60	°C
Storage temp.	Tstg.	-40	110	°C

5.2 Electro-optical Characteristics

(VDD = 5.0V, 1a = 25 C)							5 ()
	Parameter	Symbol	Condition	Min	Тур	Max	Unit
Supply current		IDD	OUTPUT terminals shall be opened	-	-	4	mA
	Low level output voltage	V _{OL}	I _{OL} = 16mA	-	-	0.35	V
Output	High level output voltage	V _{OH}	1kΩ between VDD and OUTPUT	4.9	-	-	V
	Low level circuit current	I _{OL}	-			16	mA
"Low \rightarrow High" threshold irradiance		Ee _{PLH}	Light emitting diode $(\lambda p = 940 \text{ nm})$	-	0.4	2.66	µW/mm²
"High →	Low" threshold irradiance	Ee _{PHL}	Light emitting diode $(\lambda p = 940 \text{ nm})$	-	0.4	2.8	µW/mm²
Hysteresis		E _{HYS}	-	0.45	-	0.95	-
B.P.F center Frequency		fc	-		200		kHz
Fr	equency Response	fo	-	40		300	kHz
Spectral response sensitivity		λ	-	400	-	1100	nm
Peak wavelength		λр	-	-	850	-	nm
Booponoo t	"Low \rightarrow High" propagation delay time	t _{PLH}	VDD=5V, RL = 1 kΩ	-	-	40	μs
Response t	"High → Low" propagation delay time	t _{PHL}	VDD=5V, RL = 1 kΩ	-	-	20	μs
External disturbing light illuminance		-	Eep= 7.5μW/mm², λp= 940nm	2000	-	-	lx

(VDD = 5.0V, Ta = 25 °C)

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6. Application

6.1 Application Circuit



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7. Chip Information

TP LD_SEL	
Photo Diode (306 X 306um2)	1,160um
GND OUTPUT VCC	•
660um	

PAD	X[um]	Y[um]
ТР	152.3	1038.2
LD_SEL	152.3	838.2
VSS	153.1	152.3
OUTPUT	347.3	152.3
VDD	541.2	152.3

Terminal name	Description
VDD	Supply Voltage
VSS	Ground
OUTPUT	NPN open collector output terminal.
LD_SEL	Output type selection input terminal. • Open: Light ON output • Ground : Dark ON output

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